

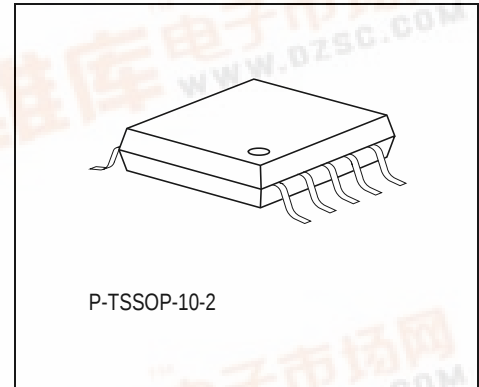


GaAs MMIC

Preliminary Data Sheet

CGY 99

- Broadband 3-stage Power Amplifier (800 ... 2400 MHz)
- GSM, AMPS, PCN, PCS
- Operating voltage range: 2.7 to 6.0 V
- $P_{out} = 35.0$ dBm at $V_D = 3.5$ V
- Overall power added efficiency 55%
- Easy external matching

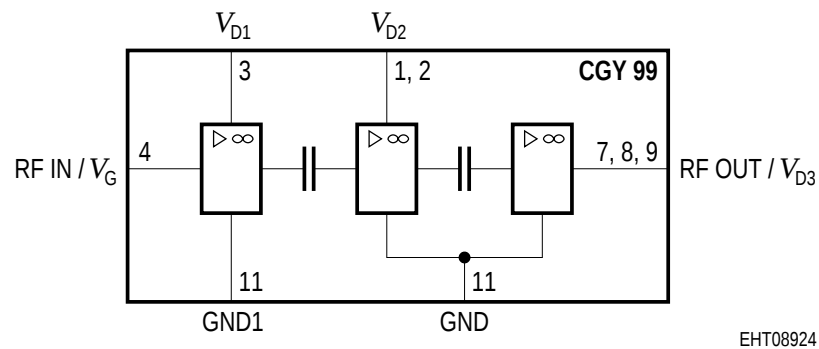


ESD: **E**lectrostatic **d**ischarge sensitive device, observe handling precautions!

Type	Marking	Ordering Code (taped)	Package
CGY 99	t.b.d.	t.b.d.	P-TSSOP-10-2

Maximum Ratings	Symbol	Value	Unit
Positive supply voltage	V_D	6	V
Channel temperature	T_{Ch}	150	°C
Storage temperature	T_{stg}	– 55 ... + 150	°C
Total power dissipation ($T_s \leq 81$ °C) T_s : Temperature at soldering point	P_{tot}	4.0	W
Pulse peak power duty cycle 12.5%, $t_{on} = 0.577$ ms	P_{Pulse}	10.0	W

Thermal Resistance	Symbol	Value	Unit
Channel-soldering point	R_{thChS}	14	K/W



EHT08924

Figure 1 Functional Block Diagram

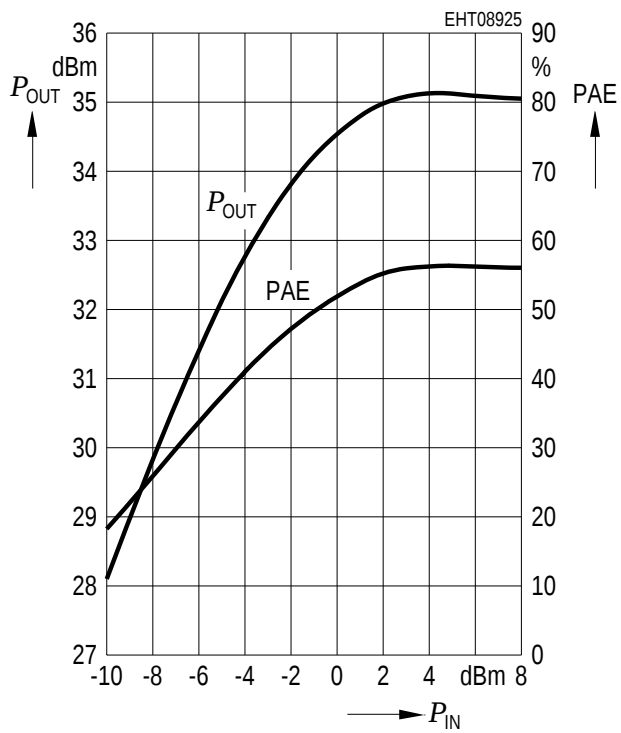
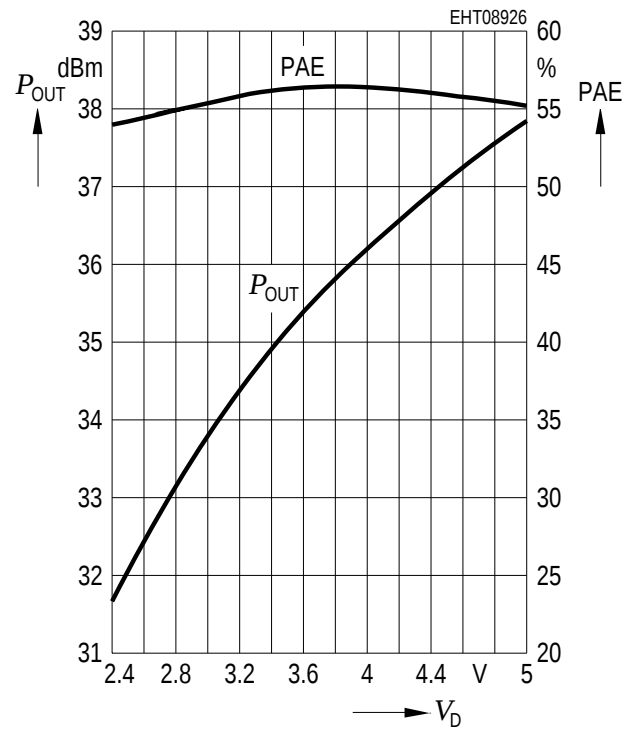
Pin #	Name	Configuration
1,2	VD2	Drain voltage 2 nd stage
3	VD1	Drain voltage 1 st stage
4	RFin/VG	RF input/gate voltage
5	n.c.	—
6	n.c.	—
7, 8, 9	VD3/RFout	RF output/drain voltage 3 rd stage
10	n.c.	—
11	GND	Ground 2 nd and 3 rd stage (backside of P-TSSOP-10-2 package)

GSM-Operation

Electrical Characteristics (On GSM Application Board)

$T_A = 25\text{ °C}$, $Z_S = Z_L = 50\text{ }\Omega$, duty cycle 12.5%, $t_{on} = 577\text{ }\mu\text{s}$, unless otherwise specified.

Parameters	Symbol	Limit Values			Unit	Test Conditions
		min.	typ.	max.		
Frequency range	f	880	–	915	MHz	–
Supply current	I_{DD}	–	1.6	–	A	$V_D = 3.5\text{ V}$, $P_{in} = +5\text{ dBm}$
Power Gain	G	–	30	–	dB	$V_D = 3.5\text{ V}$, $P_{in} = +5\text{ dBm}$
Output Power	P_o	–	33.2	–	dBm	$V_D = 2.8\text{ V}$, $P_{in} = +5\text{ dBm}$
Output Power	P_o	–	34.4	–	dBm	$V_D = 3.2\text{ V}$, $P_{in} = +5\text{ dBm}$
Output Power	P_o	–	35.0	–	dBm	$V_D = 3.5\text{ V}$, $P_{in} = +5\text{ dBm}$
Overall Power added Efficiency	PAE	–	55	–	%	$V_D = 3.5\text{ V}$, $P_{in} = +5\text{ dBm}$
Harmonics	–				dBc	–
$2f_0$		–	–40	–		
$3f_0$		–	–40	–		
Input VSWR	–	–	2 : 1	–	–	$V_D = 3.5\text{ V}$ or $V_D = 4.8\text{ V}$
Load mismatch Load VSWR = 20 : 1 for all phase	–	No module damage for 10 s.			–	$P_{in} = 5\text{ dBm}$, $V_D \leq 4.6\text{ V}$, $Z_S = 50\text{ }\Omega$
Stability Load VSWR = 5 : 1 for all phase	–	All spurious output more than 70 dB below desired signal level			–	$P_{in} = 5\text{ dBm}$, $V_D = 4.6\text{ V}$, $Z_S = 50\text{ }\Omega$

GSM-Measurements
CGY 99
 $f = 900 \text{ MHz}$, $V_D = 3.5 \text{ V}$, $V_G = -0.9 \text{ V}$

CGY 99
 $f = 900 \text{ MHz}$, $P_{in} = 5 \text{ dBm}$, $V_G = -0.9 \text{ V}$


PCN(DCS1800)-Operation

Electrical Characteristics (On GSM Application Board)

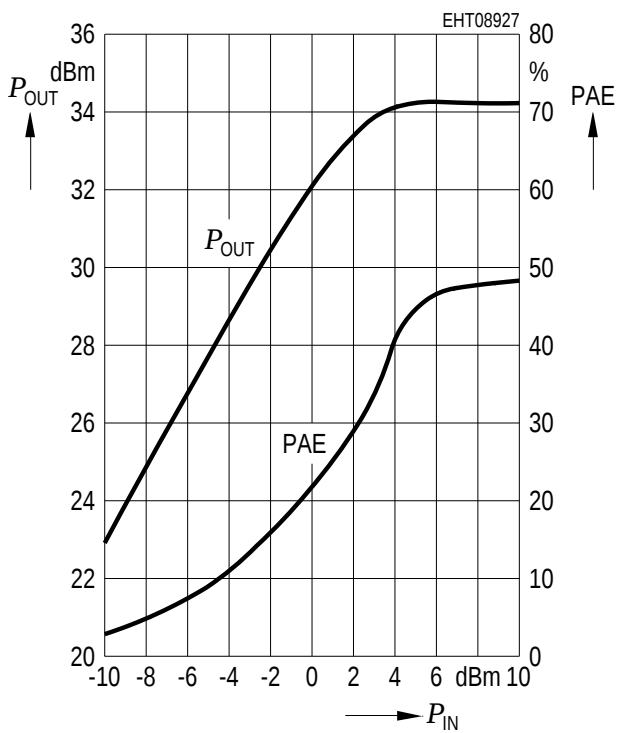
$T_A = 25\text{ °C}$, $Z_S = Z_L = 50\text{ }\Omega$, duty cycle 12.5%, $t_{on} = 577\text{ }\mu\text{s}$, unless otherwise specified.

Parameters	Symbol	Limit Values			Unit	Test Conditions
		min.	typ.	max.		
Frequency range	f	1710	–	1785	MHz	–
Supply current	I_{DD}	–	1.6	–	A	$V_D = 3.5\text{ V}$, $P_{in} = +5\text{ dBm}$
Power Gain	G	–	29	–	dB	$V_D = 3.5\text{ V}$, $P_{in} = +5\text{ dBm}$
Output Power	P_o	–	32.1	–	dBm	$V_D = 2.8\text{ V}$, $P_{in} = +5\text{ dBm}$
Output Power	P_o	–	33.4	–	dBm	$V_D = 3.2\text{ V}$, $P_{in} = +5\text{ dBm}$
Output Power	P_o	–	34.0	–	dBm	$V_D = 3.5\text{ V}$, $P_{in} = +5\text{ dBm}$
Overall Power added Efficiency	PAE	–	45	–	%	$V_D = 3.5\text{ V}$, $P_{in} = +5\text{ dBm}$
Harmonics	–	–	–	–	dBc	–
$2f_0$	–	–	–40	–		
$3f_0$	–	–	–40	–		
Input VSWR	–	–	2 : 1	–	–	$V_D = 3.5\text{ V}$ or $V_D = 4.8\text{ V}$
Load mismatch Load VSWR = 20 : 1 for all phase	–	No module damage for 10 s.			–	$P_{in} = 5\text{ dBm}$, $V_D \leq 4.6\text{ V}$, $Z_S = 50\text{ }\Omega$
Stability Load VSWR = 5 : 1 for all phase	–	All spurious output more than 70 dB below desired signal level.			–	$P_{in} = 5\text{ dBm}$, $V_D = 4.6\text{ V}$, $Z_S = 50\text{ }\Omega$

PCN-Measurements (Board Matched for Maximum Output Power)

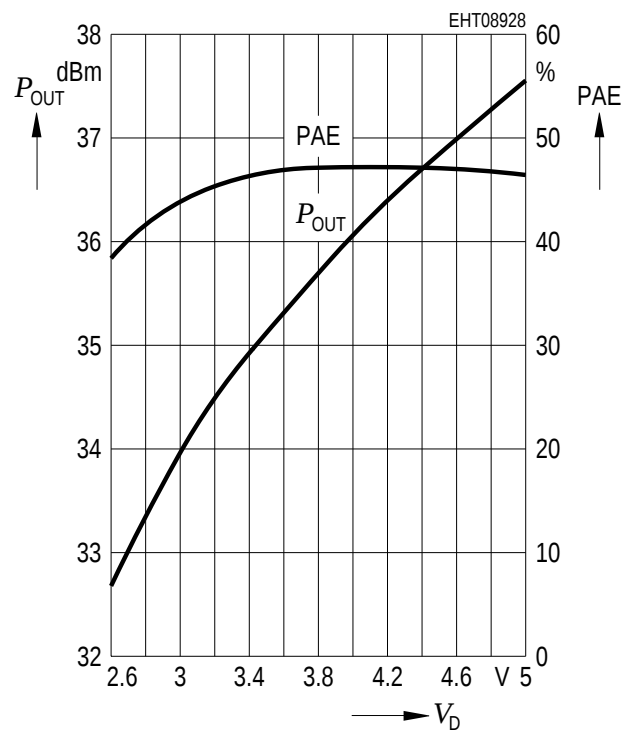
CGY 99

$f = 1750 \text{ MHz}$, $V_G = -0.58 \text{ V}$, $V_D = 3.15 \text{ V}$



CGY 99

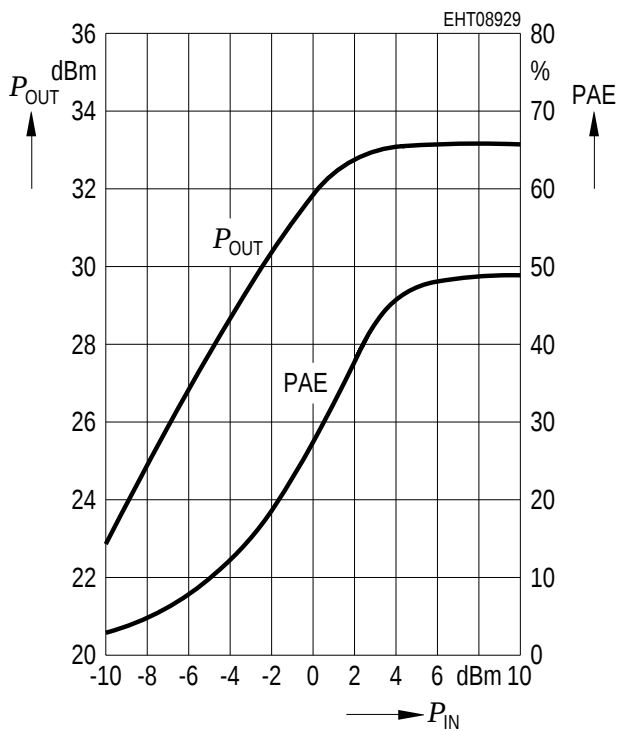
$f = 1750 \text{ MHz}$, $P_{in} = 5 \text{ dBm}$, $V_G = -0.58 \text{ V}$



PCN-Measurements (Board Matched for Reduced Output Power)

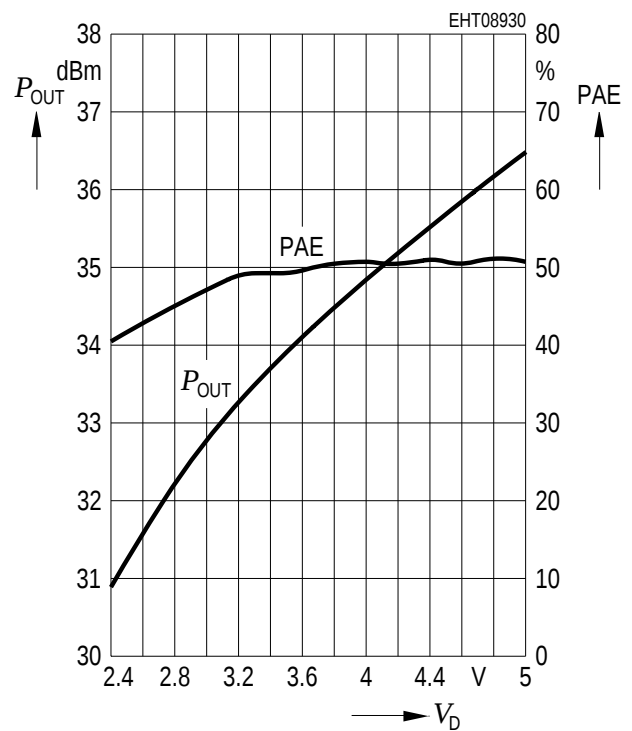
CGY 99

$f = 1750 \text{ MHz}$, $V_G = -0.58 \text{ V}$, $V_D = 3.15 \text{ V}$



CGY 99

$f = 1750 \text{ MHz}$, $P_{in} = 5 \text{ dBm}$, $V_G = -0.58 \text{ V}$



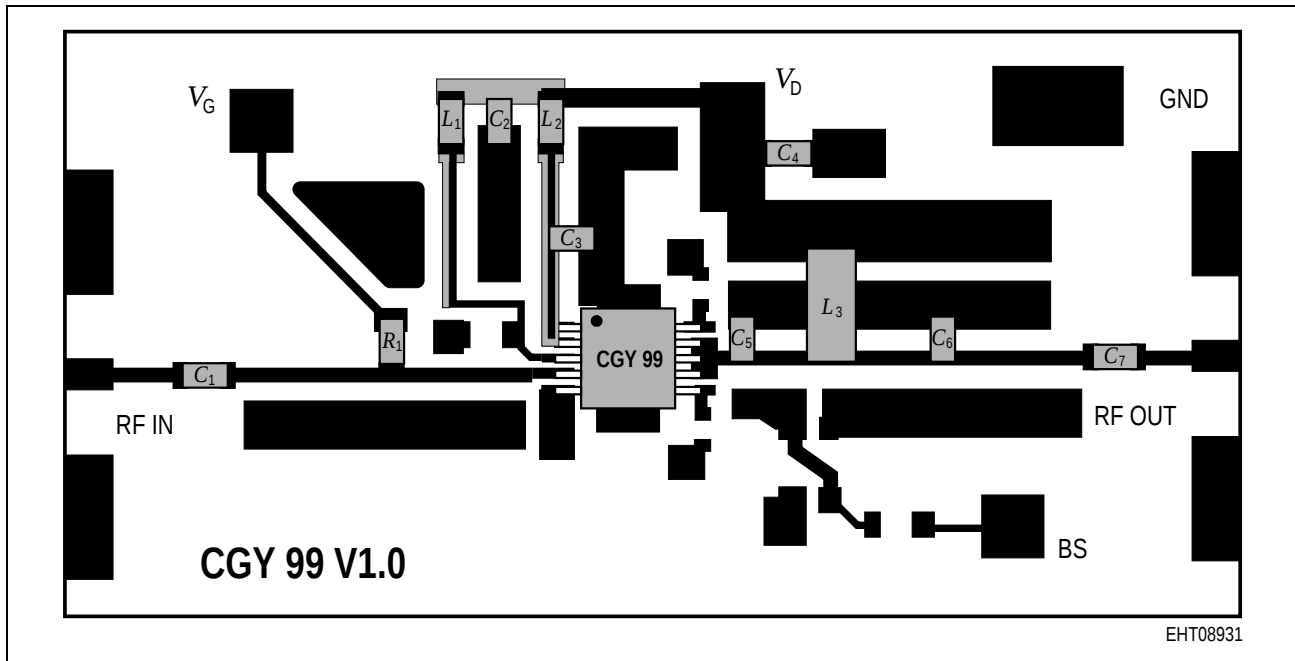


Figure 2 CGY 99 GSM Application Board

Bordmaterial: FR4/0.2 mm

Boardsize: 38 mm × 19 mm

Part List

	Value	Part Type		Value	Part Type
L_1	1.5 nH	0603	C_5	12 pF	0603 ¹⁾
L_2	39 nH	0603	C_6	8.2 pF	0603 ¹⁾
L_3	33 nH	2)	C_7	1 nF	0603
C_1	1 nF	0603	R_1	150 Ω	0603
C_2	1 nF	0603	—	—	—
C_3	1 nF	0603	—	—	—
C_4	100 nF	0603	—	—	—

¹⁾ For maximum efficiency use high quality capacitors for the output matching:

Part Number ACCU-P0603, distribution by
AVX Gmb, 85757 Karlsfeld, Germany
Phone-No +498131/9004-0

²⁾ 33 nH SMD-Inductor for drain3:

Part Number BV1250, distribution by
Horst David GmbH, 85375 Neufarn, Germany
Phone-No +498165/9548-0, Fax-No +498165/9548-28

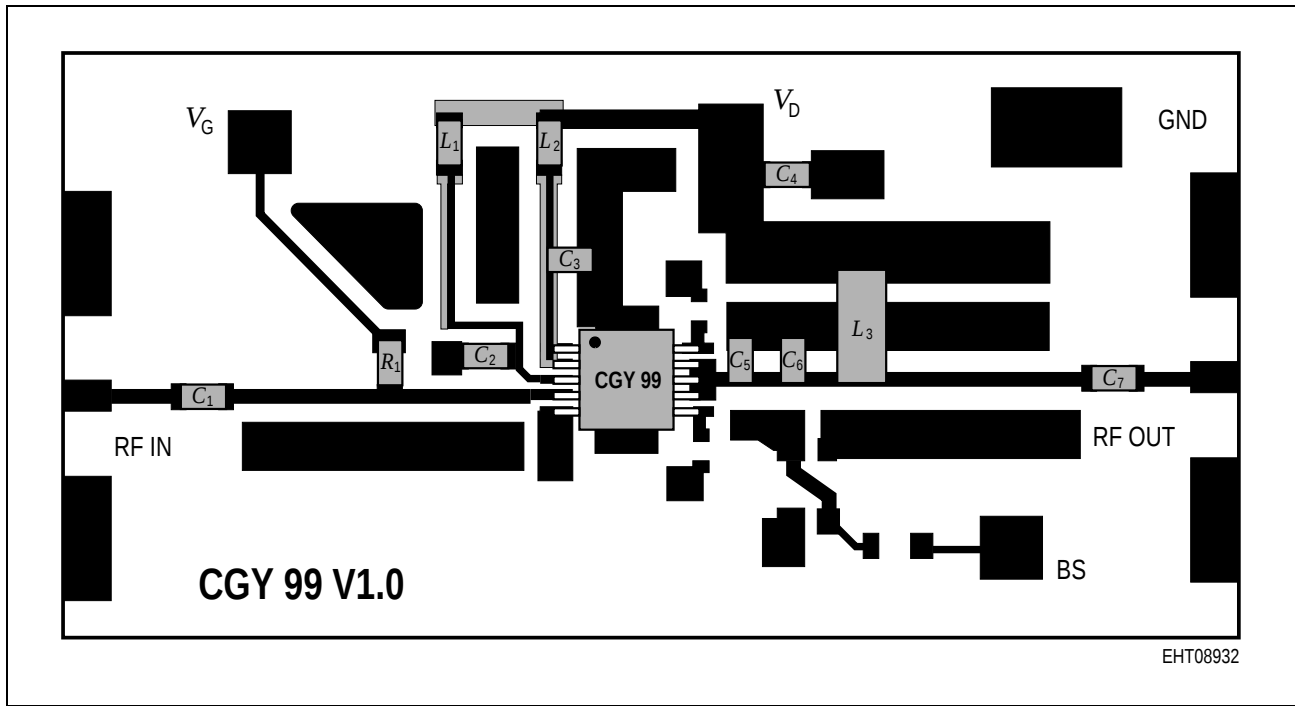


Figure 3 CGY 99 PCN Application Board

Bordmaterial: FR4/0.2 mm

Boardsize: 38 mm × 19 mm

Part List

	Value	Part Type		Value	Part Type
L_1	22 nH	0603	C_5	4.7 pF	0603 ¹⁾
L_2	22 nH	0603	C_6	2.0 pF	0603 ¹⁾
L_3	33 nH	²⁾	C_7	1 nF	0603
C_1	1 nF	0603	R_1	150 Ω	0603
C_2	56 pF	0603	—	—	—
C_3	4.7 pF	0603 ¹⁾	—	—	—
C_4	100 nF	0603	—	—	—

¹⁾ For maximum efficiency use high quality capacitors for the output matching:

Part Number ACCU-P0603, distribution by
AVX Gmb, 85757 Karlsfeld, Germany
Phone-No +498131/9004-0

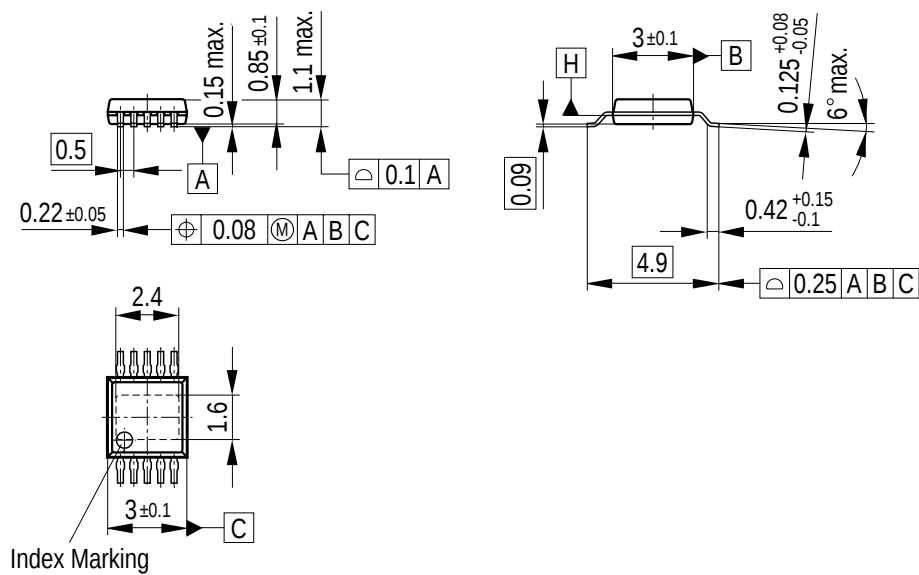
²⁾ 33 nH SMD-Inductor for drain3:

Part Number BV1250, distribution by
Horst David GmbH, 85375 Neufarn, Germany
Phone-No +498165/9548-0, Fax-No +498165/9548-28

Package Outlines

P-TSSOP-10-2

(Plastic Thin Shrink Small Outline Package)



GPS09230

Sorts of Packing

Package outlines for tubes, trays etc. are contained in our Data Book "Package Information".

SMD = Surface Mounted Device

Dimensions in mm